

# MC78XX/LM78XX/MC78XXA

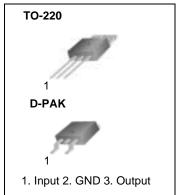
# 3-Terminal 1A Positive Voltage Regulator

#### **Features**

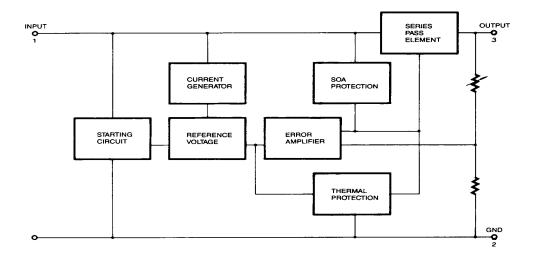
- Output Current up to 1A
- Output Voltages of 5, 6, 8, 9, 10, 12, 15, 18, 24V
- Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe Operating Area Protection

### **Description**

The MC78XX/LM78XX/MC78XXA series of three terminal positive regulators are available in the TO-220/D-PAK package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut down and safe operating area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over 1A output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltages and currents.



### **Internal Block Digram**



# **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Input Voltage (for V <sub>O</sub> = 5V to 18V) (for V <sub>O</sub> = 24V)	V <sub>I</sub> V <sub>I</sub>	35 40	V V
Thermal Resistance Junction-Cases (TO-220)	R <sub>0</sub> JC	5	°C/W
Thermal Resistance Junction-Air (TO-220)	RθJA	65	°C/W
Operating Temperature Range	TOPR	0 ~ +125	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

# **Electrical Characteristics (MC7805/LM7805)**

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI = 10V, CI= 0.33 $\mu$ F, CO= 0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Ca	onditions	MC7	805/LM	7805	Unit
Parameter	Symbol		onations	Min.	Тур.	Max.	Unit
		TJ =+25 °C		4.8	5.0	5.2	
Output Voltage	Vo	$5.0 \text{mA} \le \text{Io} \le 1.0 \text{A}, \text{PO} \le 15 \text{W}$ $\text{VI} = 7 \text{V to } 20 \text{V}$		4.75	5.0	5.25	V
Line Regulation (Note1)	Regline	T <sub>J=+25</sub> °C	Vo = 7V to 25V	-	4.0	100	mV
Line Regulation (Note I)	Regilile	11=+23 C	VI = 8V to 12V	-	1.6	50	IIIV
			IO = 5.0mA to1.5A	-	9	100	
Load Regulation (Note1)	Regload	T <sub>J</sub> =+25 °C	I <sub>O</sub> =250mA to 750mA	-	4	50	mV
Quiescent Current	IQ	TJ =+25 °C		-	5.0	8.0	mA
Quiescent Current Change	Alo	IO = 5mA to 1.	0A	-	0.03	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 7V to 25V		-	0.3	1.3	IIIA
Output Voltage Drift	ΔV0/ΔΤ	Io= 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100	OKHz, TA=+25 °C	-	42	-	μV/Vo
Ripple Rejection	RR	f = 120Hz Vo = 8V to 18V	f = 120Hz V <sub>O</sub> = 8V to 18V		73	-	dB
Dropout Voltage	V <sub>Drop</sub>	I <sub>O</sub> = 1A, T <sub>J</sub> =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	15	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =	+25 °C	-	230	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in  $V_0$  due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7806)**

(Refer to test circuit  $,0^{\circ}C < T_{J} < 125^{\circ}C, \ I_{O} = 500 \text{mA}, \ V_{I} = 11 \text{V}, \ C_{I} = 0.33 \mu\text{F}, \ C_{O} = 0.1 \mu\text{F}, \ unless otherwise specified})$ 

Parameter	Cymbal	Co	nditions	l	MC7806	;	Unit
Parameter	Symbol		maitions	Min.	Тур.	Max.	Onit
		T <sub>J</sub> =+25 °C		5.75	6.0	6.25	
Output Voltage	Vo	$\begin{array}{l} \textrm{5.0mA} \leq \textrm{I}_{\textrm{O}} \leq \textrm{1.0A, P}_{\textrm{O}} \leq \textrm{15W} \\ \textrm{V}_{\textrm{I}} = \textrm{8.0V to 21V} \end{array}$		5.7	6.0	6.3	V
Line Regulation (Note1)	Poglino	T <sub>J</sub> =+25 °C	V <sub>I</sub> = 8V to 25V	-	5	120	mV
Line Regulation (Note I)	Regline	1J =+25 C	V <sub>I</sub> = 9V to 13V	-	1.5	60	IIIV
Load Regulation (Note1)	Pagland	TJ =+25 °C	IO =5mA to 1.5A	-	9	120	mV
Load Regulation (Note I)	Regload	1J=+25 C	IO =250mA to750A	-	3	60	IIIV
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.0	8.0	mA
Quiescent Current Change	Ma	I <sub>O</sub> = 5mA to 1A		-	-	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 8V to 25V		-	-	1.3	IIIA
Output Voltage Drift	ΔV0/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100K	Hz, TA =+25 °C	-	45	-	μV/Vo
Ripple Rejection	RR	f = 120Hz V <sub>I</sub> = 9V to 19V		59	75	-	dB
Dropout Voltage	V <sub>Drop</sub>	I <sub>O</sub> = 1A, T <sub>J</sub> =+25 °C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	19	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+2	25 °C	-	250	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7808)**

(Refer to test circuit ,0°C < T<sub>J</sub> < 125°C, I<sub>O</sub> = 500mA, V<sub>I</sub> =14V, C<sub>I</sub>= 0.33 $\mu$ F, C<sub>O</sub>= 0.1 $\mu$ F, unless otherwise specified)

Devemeter	Cumbal	6.	an dition o	N	/IC780	8	Unit
Parameter	Symbol		onditions	Min.	Тур.	Max.	Unit
		TJ =+25 °C		7.7	8.0	8.3	
Output Voltage	Vo	$5.0 \text{mA} \le I_0 \le 1$ V <sub>I</sub> = 10.5V to 23		7.6	8.0	8.4	V
Line Demulation (Nated)	Danka	T05.00	V <sub>I</sub> = 10.5V to 25V	-	5.0	160	\/
Line Regulation (Note1)	Regline	TJ =+25 °C	V <sub>I</sub> = 11.5V to 17V	-	2.0	80	mV
Load Regulation (Note1)	Doglood	T25 °C	I <sub>O</sub> = 5.0mA to 1.5A	-	10	160	m\/
Load Regulation (Note1)	Regload	TJ =+25 °C	Io= 250mA to 750mA	-	5.0	80	mV
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.0	8.0	mA
Quiagont Current Change	41-	I <sub>O</sub> = 5mA to 1.0A	<del>J</del>	-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 10.5A to 25	V	-	0.5	1.0	mA
Output Voltage Drift	ΔV0/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	Hz, TA =+25 °C	-	52	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, V <sub>I</sub> = 1	1.5V to 21.5V	56	73	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ=+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	VI= 35V, TA =+2	5 °C	-	230	-	mA
Peak Current	IPK	T <sub>J</sub> =+25 °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7809)**

(Refer to test circuit ,0°C < T<sub>J</sub> < 125°C, I<sub>O</sub> = 500mA, V<sub>I</sub> =15V, C<sub>I</sub>= 0.33 $\mu$ F, C<sub>O</sub>= 0.1 $\mu$ F, unless otherwise specified)

Parameter	Cymbal	Co	onditions	ı	MC7809	)	Unit
Parameter	Symbol		onditions	Min.	Тур.	Max.	Unit
		TJ =+25°C		8.65	9	9.35	
Output Voltage	Vo	5.0mA≤ I <sub>O</sub> ≤1.0A V <sub>I</sub> = 11.5V to 24V	•	8.6	9	9.4	V
Line Degulation (Note1)	Dogling	T25°C	V <sub>I</sub> = 11.5V to 25V	-	6	180	m\/
Line Regulation (Note1)	Regline	TJ=+25°C	VI = 12V to 17V	-	2	90	mV
Load Regulation (Note1)	Dogland	T25°C	I <sub>O</sub> = 5mA to 1.5A	-	12	180	m\/
Load Regulation (Note1)	Regload	TJ=+25°C	IO = 250mA to 750mA	-	4	90	mV
Quiescent Current	IQ	T <sub>J</sub> =+25°C		-	5.0	8.0	mA
Quiescent Current Change	Mo	$I_0 = 5 \text{mA to } 1.0 \text{A}$	1	-	-	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 11.5V to 26	V	-	-	1.3	IIIA
Output Voltage Drift	ΔV0/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	lz, T <sub>A</sub> =+25 °C	-	58	-	μV/Vo
Ripple Rejection	RR	f = 120Hz V <sub>I</sub> = 13V to 23V			71	-	dB
Dropout Voltage	V <sub>Drop</sub>	Io = 1A, T <sub>J</sub> =+25°C		-	2	-	V
Output Resistance	ro	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+2	5°C	-	250	-	mA
Peak Current	IPK	TJ= +25°C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7810)**

(Refer to test circuit ,0°C< TJ < 125°C, IO = 500mA, VI =16V, CI=  $0.33\mu F$ , CO= $0.1\mu F$ , unless otherwise specified)

Parameter	Symbol Conditions			MC7810	)	Unit	
Parameter	Symbol		onations	Min.	Тур.	Max.	Unit
		TJ =+25 °C		9.6	10	10.4	
Output Voltage	Vo	5.0mA ≤ I <sub>O</sub> ≤1.0A V <sub>I</sub> = 12.5V to 25		9.5	10	10.5	V
Line Degulation (Noted)	Doglino	T 25°C	V <sub>I</sub> = 12.5V to 25V	1	10	200	\/
Line Regulation (Note1)	Regline	TJ =+25°C	VI = 13V to 25V	•	3	100	- mV
Load Regulation (Note1)	Dogland	T25°C	I <sub>O</sub> = 5mA to 1.5A	-	12	200	m\/
Load Regulation (Note1)	Regload	TJ =+25°C	IO = 250mA to 750mA	1	4	400	- mV
Quiescent Current	IQ	T <sub>J</sub> =+25°C		1	5.1	8.0	mA
Quinagent Current Change	Mo	$I_0 = 5 \text{mA to } 1.0 \text{A}$	4	1	-	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 12.5V to 29	V	-	-	1.0	IIIA
Output Voltage Drift	ΔV0/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	łz, TA =+25 °C	-	58	-	μV/Vo
Ripple Rejection	RR	f = 120Hz V <sub>I</sub> = 13V to 23V			71	-	dB
Dropout Voltage	V <sub>Drop</sub>	Io = 1A, T <sub>J</sub> =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+2	5 °C	-	250	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	Α

#### Note

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7812)**

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI =19V, CI= 0.33 $\mu$ F, CO=0.1 $\mu$ F, unless otherwise specified)

Donomotor	Cymphol	Conditions		MC7812			Unit
Parameter	Symbol		onations	Min.	Тур.	Max.	Unit
		TJ =+25 °C		11.5	12	12.5	
Output Voltage	Vo	5.0mA ≤ I <sub>O</sub> ≤1.0A V <sub>I</sub> = 14.5V to 27\		11.4	12	12.6	V
Line Degulation (Nated)	Dogling	T25 90	V <sub>I</sub> = 14.5V to 30V	-	10	240	m) /
Line Regulation (Note1)	Regline	TJ =+25 °C	VI = 16V to 22V	-	3.0	120	mV
Load Regulation (Note1)	Regload	TJ =+25 °C	I <sub>O</sub> = 5mA to 1.5A	-	11	240	mV
Load Regulation (Note1)	Regioad	1J=+25 C	IO = 250mA to 750mA	-	5.0	120	IIIV
Quiescent Current	IQ	TJ =+25 °C		-	5.1	8.0	mA
Quiescent Current Change	Alo	IO = 5mA to 1.0A	1	-	0.1	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 14.5V to 30\	/	-	0.5	1.0	ША
Output Voltage Drift	ΔV0/ΔΤ	IO = 5mA		-	-1	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 100KH	z, TA =+25 °C	-	76	-	μV/Vo
Ripple Rejection	RR	f = 120Hz V <sub>I</sub> = 15V to 25V		55	71	-	dB
Dropout Voltage	V <sub>Drop</sub>	I <sub>O</sub> = 1A, T <sub>J</sub> =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	18	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+2	5°C	-	230	-	mA
Peak Current	IPK	TJ = +25 °C		-	2.2	-	Α

#### Note

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7815)**

(Refer to test circuit ,0°C < T<sub>J</sub> < 125°C, I<sub>O</sub> = 500mA, V<sub>I</sub> =23V, C<sub>I</sub>= 0.33 $\mu$ F, C<sub>O</sub>=0.1 $\mu$ F, unless otherwise specified)

Parameter	Cumbal	Conditions			MC7815	)	Unit
Parameter	Symbol		onanions	Min.	Тур.	Max.	Onit
		TJ =+25 °C		14.4	15	15.6	
Output Voltage	Vo	$5.0\text{mA} \le I_O \le 1.0\text{A}, P_O \le 15\text{W}$ VI = 17.5V to 30V		14.25	15	15.75	V
Line Regulation (Nete1)	Doglino	TJ =+25 °C	V <sub>I</sub> = 17.5V to 30V	-	11	300	mV
Line Regulation (Note1)	Regline	1J=+25 C	V <sub>I</sub> = 20V to 26V	-	3	150	IIIV
			I <sub>O</sub> = 5mA to 1.5A	-	12	300	
Load Regulation (Note1)	Regload		IO = 250mA to 750mA	-	4	150	mV
Quiescent Current	IQ	TJ =+25 °C		-	5.2	8.0	mA
Quiagant Current Change	A.I.O.	I <sub>O</sub> = 5mA to 1	.0A	-	-	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 17.5V to 3	30V	-	-	1.0	
Output Voltage Drift	ΔV <sub>O</sub> /ΔT	I <sub>O</sub> = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100	KHz, T <sub>A</sub> =+25 °C	-	90	-	μV/Vo
Ripple Rejection	RR	f = 120Hz V <sub>I</sub> = 18.5V to 2	f = 120Hz VI = 18.5V to 28.5V		70	-	dB
Dropout Voltage	V <sub>Drop</sub>	I <sub>O</sub> = 1A, T <sub>J</sub> =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	19	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =	+25 °C	-	250	-	mA
Peak Current	IPK	T <sub>J</sub> =+25 °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7818)**

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI =27V, CI= 0.33 $\mu$ F, CO=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	C	onditions	N	/IC7818	В	Unit
Parameter	Symbol		onations	Min.	Тур.	Max.	Onit
		TJ =+25 °C		17.3	18	18.7	
Output Voltage	Vo	5.0mA ≤ I <sub>O</sub> ≤1.0A V <sub>I</sub> = 21V to 33V	A, P <sub>O</sub> ≤15W	17.1	18	18.9	V
Line Degulation (Note1)	Dogling	TJ =+25 °C	V <sub>I</sub> = 21V to 33V	-	15	360	mV
Line Regulation (Note1)	Regline	1J=+25 C	VI = 24V to 30V	-	5	180	IIIV
Load Regulation (Note1)	Regload	TJ =+25 °C	I <sub>O</sub> = 5mA to 1.5A	-	15	360	mV
Load Regulation (Note1)	Regioad	1J=+25 C	IO = 250mA to 750mA	-	5.0	180	IIIV
Quiescent Current	IQ	TJ =+25 °C		-	5.2	8.0	mA
Quiagant Current Change	ΔIO	IO = 5mA to 1.0A		-	-	0.5	mΛ
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 21V to 33V		-	-	1	mA
Output Voltage Drift	ΔV0/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	z, TA =+25 °C	-	110	-	μV/Vo
Ripple Rejection	RR	f = 120Hz V <sub>I</sub> = 22V to 32V			69	-	dB
Dropout Voltage	V <sub>Drop</sub>	I <sub>O</sub> = 1A, T <sub>J</sub> =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	22	-	mΩ
Short Circuit Current	Isc	VI = 35V, T <sub>A</sub> =+25	5°C	-	250	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7824)**

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI =33V, CI= 0.33 $\mu$ F, CO=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Conditions		N	MC7824		
Parameter	Symbol		Diamons	Min.	Тур.	Max.	Unit
		TJ =+25 °C		23	24	25	
Output Voltage	Vo	5.0mA ≤ I <sub>O</sub> ≤ 1.0. VI = 27V to 38V	A, P <sub>O</sub> ≤ 15W	22.8	24	25.25	V
Line Regulation (Note1)	Poglino	TJ =+25 °C	V <sub>I</sub> = 27V to 38V	-	17	480	
Line Regulation (Note1)	Regline	1J=+25 C	VI = 30V to 36V	-	6	240	mV
Load Population (Note1)	Poglood	TJ =+25 °C	I <sub>O</sub> = 5mA to 1.5A	-	15	480	mV
Load Regulation (Note1)	Regload	1J=+25 C	IO = 250mA to 750mA	-	5.0	240	IIIV
Quiescent Current	IQ	TJ =+25 °C		-	5.2	8.0	mA
Quiescent Current Change	Alo	IO = 5mA to 1.0A	1	-	0.1	0.5	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 27V to 38V		-	0.5	1	IIIA
Output Voltage Drift	ΔV0/ΔΤ	IO = 5mA		-	-1.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KH	z, TA =+25 °C	-	60	-	μV/Vo
Ripple Rejection	RR	f = 120Hz V <sub>I</sub> = 28V to 38V		50	67	-	dB
Dropout Voltage	V <sub>Drop</sub>	Io = 1A, T <sub>J</sub> =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	28	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+2	5 °C	-	230	-	mA
Peak Current	IPK	TJ =+25 °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Changes in V<sub>O</sub> due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7805A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_0$  =1A, V I = 10V, C I=0.33 $\mu$ F, C O=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> =+25 °C		4.9	5	5.1	
Output Voltage	Vo	IO = 5mA to 1 V <sub>I</sub> = 7.5V to 2		4.8	5	5.2	V
		V <sub>I</sub> = 7.5V to 2 I <sub>O</sub> = 500mA	V <sub>I</sub> = 7.5V to 25V I <sub>O</sub> = 500mA		5	50	
Line Regulation (Note1)	Regline	VI = 8V to 12	V	-	3	50	mV
		T <sub>J</sub> =+25 °C	V <sub>I</sub> = 7.3V to 20V	-	5	50	-
		1J=+25°C	V <sub>I</sub> = 8V to 12V	-	1.5	25	1
Load Regulation (Note1)		T <sub>J</sub> =+25 °C I <sub>O</sub> = 5mA to 1	T <sub>J</sub> =+25 °C I <sub>O</sub> = 5mA to 1.5A		9	100	.,
<b>5</b> ( ,	Regload	IO = 5mA to 1A		-	9	100	mV
		IO = 250mA to	o 750mA	-	4	50	
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.0	6	mA
0: 10 1		IO = 5mA to 1A		-	-	0.5	
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 8 V to 25V, I <sub>O</sub> = 500mA		-	-	0.8	mA
Onlango		V <sub>I</sub> = 7.5V to 20V, T <sub>J</sub> =+25 °C		-	-	0.8	
Output Voltage Drift	ΔV/ΔΤ	lo = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 10 T <sub>A</sub> =+25 °C	00KHz	-	10	-	μV/Vo
Ripple Rejection	RR		f = 120Hz, I <sub>O</sub> = 500mA V <sub>I</sub> = 8V to 18V			-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =	+25 °C	-	2	-	V
Output Resistance	rO	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	VI= 35V, TA =	=+25 °C	-	250	-	mA
Peak Current	IPK	T <sub>J</sub> = +25 °C		-	2.2	-	А

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7806A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_0$  =1A, V I =11V, C I=0.33 $\mu$ F, C O=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> =+25 °C		5.58	6	6.12	
Output Voltage	Vo	IO = 5mA to 1 VI = 8.6V to 2	• -	5.76	6	6.24	V
		V <sub>I</sub> = 8.6V to 25 I <sub>O</sub> = 500mA	5V	-	5	60	
Line Regulation (Note1)	Regline	V <sub>I</sub> = 9V to 13V	1	-	3	60	mV
		T <sub>J</sub> =+25 °C	V <sub>I</sub> = 8.3V to 21V	-	5	60	
		1J=+25 °C	V <sub>I</sub> = 9V to 13V	-	1.5	30	
Load Regulation (Note1)		T <sub>J</sub> =+25 °C I <sub>O</sub> = 5mA to 1	.5A	-	9	100	
Load (togalation (troto))	Regload	I <sub>O</sub> = 5mA to 1	A	-	4	100	mV
		IO = 250mA to	o 750mA	-	5.0	50	
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	4.3	6	mA
		IO = 5mA to 1A		-	-	0.5	
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 9V to 25V, I <sub>O</sub> = 500mA		-	-	8.0	mA
		VI= 8.5V to 21V, TJ =+25 °C		-	-	8.0	
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA		-	-0.8	•	mV/°C
Output Noise Voltage	VN	f = 10Hz to 10 T <sub>A</sub> =+25 °C	00KHz	-	10	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, IO = 500mA VI = 9V to 19V		-	65	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	VI= 35V, TA =	-+25 °C	-	250	-	mA
Peak Current	IPK	T <sub>J=+25</sub> °C		-	2.2	ı	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7808A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_{0}$  =1A, V I = 14V, C I=0.33 $\mu$ F, C I=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> =+25 °C		7.84	8	8.16	
Output Voltage	Vo	-	I <sub>O</sub> = 5mA to 1A, P <sub>O</sub> ≤15W V <sub>I</sub> = 10.6V to 23V		8	8.3	V
		V <sub>I</sub> = 10.6V to 2 I <sub>O</sub> = 500mA	25V	-	6	80	
Line Regulation (Note1)	Regline	V <sub>I</sub> = 11V to 17	V	-	3	80	mV
		TJ =+25 °C	V <sub>I</sub> = 10.4V to 23V	-	6	80	
		1J=+25 °C	V <sub>I</sub> = 11V to 17V	-	2	40	
Load Regulation (Note1)		T <sub>J</sub> =+25 °C I <sub>O</sub> = 5mA to 1	1.5A	-	12	100	
	Regload	I <sub>O</sub> = 5mA to 1A		-	12	100	mV
		IO = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.0	6	mA
		IO = 5mA to 1A		-	-	0.5	
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 11V to 25V, I <sub>O</sub> = 500mA		-	-	0.8	mA
		V <sub>I</sub> = 10.6V to 23V, T <sub>J</sub> =+25 °C		-	-	0.8	İ
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KHz T <sub>A</sub> =+25 °C		-	10	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I <sub>O</sub> = 500mA V <sub>I</sub> = 11.5V to 21.5V		-	62	-	dB
Dropout Voltage	V <sub>Drop</sub>	I <sub>O</sub> = 1A, T <sub>J</sub> =+25 °C		-	2	-	V
Output Resistance	rO	f = 1KHz		-	18	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+25 °C		-	250	-	mA
Peak Current	IPK	TJ=+25 °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7809A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_0$  =1A, V I = 15V, C I=0.33 $\mu$ F, C I=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> =+25°C		8.82	9.0	9.18	
Output Voltage	Vo		IO = 5mA to 1A, PO≤15W VI = 11.2V to 24V		9.0	9.35	V
		V <sub>I</sub> = 11.7V to 2 I <sub>O</sub> = 500mA	25V	-	6	90	
Line Regulation (Note1)	Regline	V <sub>I</sub> = 12.5V to	19V	-	4	45	mV
		T,j =+25°C	V <sub>I</sub> = 11.5V to 24V	-	6	90	
		15 = +25 C	V <sub>I</sub> = 12.5V to 19V	-	2	45	
Load Regulation (Note1)		T <sub>J</sub> =+25°C I <sub>O</sub> = 5mA to 1	.0A	-	12	100	
(	Regload	I <sub>O</sub> = 5mA to 1.0A		-	12	100	mV
		IO = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.0	6.0	mA
	ΔlQ	V <sub>I</sub> = 11.7V to 25V, T <sub>J</sub> =+25 °C		-	-	0.8	
Quiescent Current Change		V <sub>I</sub> = 12V to 25V, I <sub>O</sub> = 500mA		-	-	0.8	mA
		IO = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA		-	-1.0	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 10 T <sub>A</sub> =+25 °C	00KHz	-	10	-	μV/Vο
Ripple Rejection	RR	f = 120Hz, I <sub>O</sub> = 500mA V <sub>I</sub> = 12V to 22V		-	62	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25 °C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	VI= 35V, TA =+25 °C		-	250	-	mA
Peak Current	IPK	T <sub>J=+25</sub> °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant, junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7810A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_0$  =1A, V I = 16V, C I=0.33 $\mu$ F, C I=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> =+25°C		9.8	10	10.2	
Output Voltage	Vo	$I_O = 5mA \text{ to } 1A, P_O \le 15W$ V <sub>I</sub> = 12.8V to 25V		9.6	10	10.4	V
		V <sub>I</sub> = 12.8V to I <sub>O</sub> = 500mA	26V	-	8	100	
Line Regulation (Note1)	Regline	V <sub>I</sub> = 13V to 20	)V	-	4	50	mV
		T <sub>J</sub> =+25 °C	V <sub>I</sub> = 12.5V to 25V	-	8	100	
		1J =+25 C	V <sub>I</sub> = 13V to 20V	-	3	50	
Load Regulation (Note1)	Load Regulation (Note1)		T <sub>J</sub> =+25 °C I <sub>O</sub> = 5mA to 1.5A		12	100	.,
	Regload	I <sub>O</sub> = 5mA to 1.0A		-	12	100	mV
		IO = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.0	6.0	mA
		V <sub>I</sub> = 13V to 26V, T <sub>J</sub> =+25 °C		-	-	0.5	
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 12.8V to 25V, I <sub>O</sub> = 500mA		-	-	0.8	mA
		IO = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA		-	-1.0	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 1 T <sub>A</sub> =+25 °C	00KHz	-	10	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, IO = 500mA VI = 14V to 24V		-	62	-	dB
Dropout Voltage	VDrop	Io = 1A, T <sub>J</sub> =+25°C		-	2.0	-	V
Output Resistance	rO	f = 1KHz		-	17	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+25 °C		-	250	-	mA
Peak Current	lpk	TJ=+25 °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7812A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_0$  =1A, V I = 19V, C I=0.33 $\mu$ F, C I=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T <sub>J</sub> =+25 °C		11.75	12	12.25	V
Output Voltage	Vo	IO = 5mA to 7 V <sub>I</sub> = 14.8V to	1A, Po ≤15W 27V	11.5	12	12.5	
		V <sub>I</sub> = 14.8V to I <sub>O</sub> = 500mA	30V	-	10	120	
Line Regulation (Note1)	Regline	V <sub>I</sub> = 16V to 22	2V	-	4	120	mV
		T <sub>J</sub> =+25 °C	V <sub>I</sub> = 14.5V to 27V	-	10	120	
		1J=+25 C	V <sub>I</sub> = 16V to 22V	-	3	60	
Load Regulation (Note1)		T <sub>J</sub> =+25 °C I <sub>O</sub> = 5mA to 1.5A		-	12	100	.,
	Regload	IO = 5mA to 1.0A		-	12	100	mV -
		IO = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	T <sub>J</sub> =+25°C		-	5.1	6.0	mA
		V <sub>I</sub> = 15V to 30V, T <sub>J</sub> =+25 °C		-		0.8	
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 14V to 27V, I <sub>O</sub> = 500mA		-		0.8	mA
		IO = 5mA to 1.0A		-		0.5	
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA		-	-1.0	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KHz T <sub>A</sub> =+25°C		-	10	-	μV/Vο
Ripple Rejection	RR	f = 120Hz, IO = 500mA VI = 14V to 24V		-	60	-	dB
Dropout Voltage	VDrop	IO = 1A, T <sub>J</sub> =+25°C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	18	ı	mΩ
Short Circuit Current	Isc	VI= 35V, TA :	=+25 °C	-	250	-	mA
Peak Current	IPK	T <sub>J=+25</sub> °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7815A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_0$  =1A, V I =23V, C I=0.33 $\mu$ F, C O=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol		nditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> =+25 °C		14.7	15	15.3	
Output Voltage	Vo	-	$IO = 5mA \text{ to } 1A, PO \le 15W$ V <sub>I</sub> = 17.7V to 30V		15	15.6	V
		V <sub>I</sub> = 17.9V to 1 I <sub>O</sub> = 500mA	30V	-	10	150	
Line Regulation (Note1)	Regline	V <sub>I</sub> = 20V to 26	V	-	5	150	mV
		T <sub>J</sub> =+25°C	V <sub>I</sub> = 17.5V to 30V	-	11	150	
		1J=+25 C	V <sub>I</sub> = 20V to 26V	-	3	75	-
Load Regulation (Note1)		$T_J = +25 \degree C$ IO = 5mA to 1	T <sub>J</sub> =+25 °C I <sub>O</sub> = 5mA to 1.5A		12	100	
Load Rogaldion (Noto1)	Regload	I <sub>O</sub> = 5mA to 1.0A		-	12	100	mV
		IO = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.2	6.0	mA
		V <sub>I</sub> = 17.5V to 30V, T <sub>J</sub> =+25 °C		-	-	0.8	mA
Quiescent Current Change	ΔlQ	V <sub>I</sub> = 17.5V to 30V, I <sub>O</sub> = 500mA		-	-	0.8	
		IO = 5mA to 1	I.0A	-	-	0.5	-
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA		-	-1.0	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KHz T <sub>A</sub> =+25 °C		-	10	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, IO = 500mA VI = 18.5V to 28.5V		-	58	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25 °C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	19	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+25 °C		-	250	-	mA
Peak Current	IPK	T <sub>J=+25</sub> °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7818A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_0$  =1A, V I = 27V, C I=0.33 $\mu$ F, C I=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		TJ =+25 °C		17.64	18	18.36	
Output Voltage	Vo	IO = 5mA to 1A, PO ≤15W VI = 21V to 33V		17.3	18	18.7	V
		V <sub>I</sub> = 21V to 33 I <sub>O</sub> = 500mA	3V	-	15	180	
Line Regulation (Note1)	Regline	V <sub>I</sub> = 21V to 33	3V	-	5	180	mV
		T <sub>J</sub> =+25 °C	V <sub>I</sub> = 20.6V to 33V	-	15	180	
		1) =+25 C	VI= 24V to 30V	-	5	90	
Load Regulation (Note1)		T <sub>J</sub> =+25°C I <sub>O</sub> = 5mA to 1.5A		-	15	100	.,
	Regload	I <sub>O</sub> = 5mA to 1.0A		-	15	100	mV
		IO = 250mA to 750mA		-	7	50	
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.2	6.0	mA
		V <sub>I</sub> = 21V to 33V, T <sub>J</sub> =+25 °C		-	-	0.8	
Quiescent Current Change	$\Delta$ lQ	V <sub>I</sub> = 21V to 33V, I <sub>O</sub> = 500mA		-	-	0.8	mA
		IO = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA		-	-1.0	-	mV/ °C
Output Noise Voltage	VN	f = 10Hz to 1 T <sub>A</sub> =+25°C	00KHz	-	10	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, IO = 500mA VI = 22V to 32V		-	57	-	dB
Dropout Voltage	VDrop	Io = 1A, T <sub>J</sub> =+25°C		-	2.0	-	V
Output Resistance	rO	f = 1KHz		-	19	-	mΩ
Short Circuit Current	Isc	V <sub>I</sub> = 35V, T <sub>A</sub> =+25°C		-	250	-	mA
Peak Current	IPK	T <sub>J=+25</sub> °C		-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Electrical Characteristics (MC7824A)**

(Refer to the test circuits.  $0^{\circ}$ C < T<sub>J</sub> <  $125^{\circ}$ C,  $I_0$  =1A, V I = 33V, C I=0.33 $\mu$ F, C O=0.1 $\mu$ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T <sub>J</sub> =+25 °C		23.5	24	24.5	
Output Voltage	Vo	VO IO = 5mA to 1A, PO $\leq$ 15W VI = 27.3V to 38V		23	24	25	V
		V <sub>I</sub> = 27V to 38 I <sub>O</sub> = 500mA	3V	-	18	240	
Line Regulation (Note1)	Regline	V <sub>I</sub> = 21V to 33	BV	-	6	240	mV
		T <sub>J</sub> =+25 °C	V <sub>I</sub> = 26.7V to 38V	-	18	240	
		1J =+25 C	VI= 30V to 36V	-	6	120	
Load Regulation (Note1)		T <sub>J</sub> =+25 °C I <sub>O</sub> = 5mA to 1.5A		-	15	100	.,
Load Hogalation (Hotor)	Regload	I <sub>O</sub> = 5mA to 1.0A		-	15	100	mV
		IO = 250mA to 750mA		-	7	50	
Quiescent Current	IQ	T <sub>J</sub> =+25 °C		-	5.2	6.0	mA
	ΔlQ	V <sub>I</sub> = 27.3V to 38V, T <sub>J</sub> =+25 °C		-	-	0.8	
Quiescent Current Change		V <sub>I</sub> = 27.3V to 38V, I <sub>O</sub> = 500mA		-	-	0.8	mA
		IO = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA		-	-1.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KHz T <sub>A</sub> = 25 °C		-	10	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, IO = 500mA VI = 28V to 38V		-	54	-	dB
Dropout Voltage	VDrop	Io = 1A, T <sub>J</sub> =+25 °C		-	2.0	-	V
Output Resistance	ro	f = 1KHz		-	20	-	mΩ
Short Circuit Current	Isc	VI= 35V, TA =	=+25 °C	-	250	-	mA
Peak Current	IPK	T <sub>J=+25</sub> °C	-	-	2.2	-	Α

<sup>1.</sup> Load and line regulation are specified at constant junction temperature. Change in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

# **Typical Perfomance Characteristics**

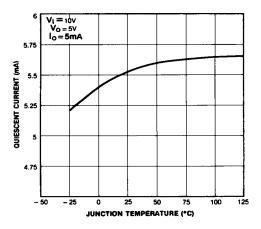


Figure 1. Quiescent Current

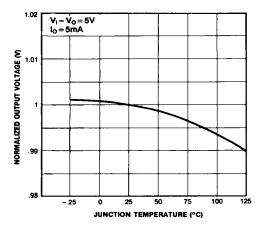


Figure 3. Output Voltage

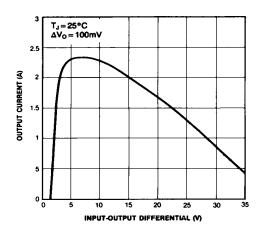


Figure 2. Peak Output Current

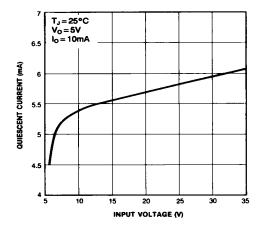


Figure 4. Quiescent Current

# **Typical Applications**

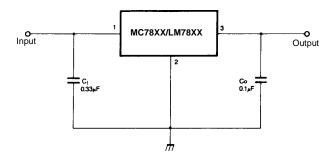


Figure 5. DC Parameters

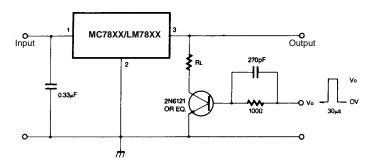


Figure 6. Load Regulation

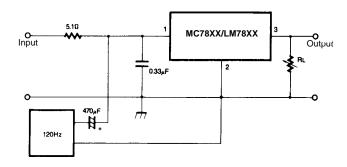


Figure 7. Ripple Rejection

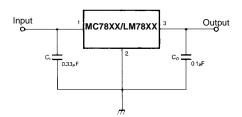


Figure 8. Fixed Output Regulator

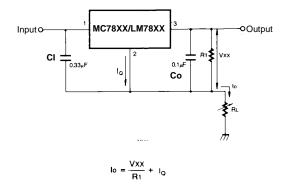
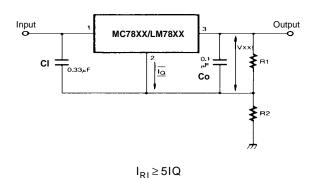


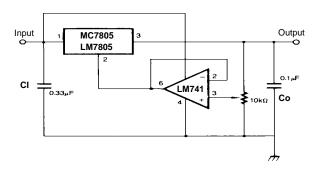
Figure 9. Constant Current Regulator

- (1) To specify an output voltage. substitute voltage value for "XX." A common ground is required between the input and the Output voltage. The input voltage must remain typically 2.0V above the output voltage even during the low point on the input ripple voltage.
- (2) C<sub>I</sub> is required if regulator is located an appreciable distance from power Supply filter.
- (3) Co improves stability and transient response.



 $V_O = V_{XX}(1+R_2/R_1)+I_QR_2$ 

Figure 10. Circuit for Increasing Output Voltage



 $I_{RI} \ge 5 I_{Q}$   $V_{Q} = V_{XX}(1+R_{2}/R_{1})+I_{Q}R_{2}$ 

Figure 11. Adjustable Output Regulator (7 to 30V)

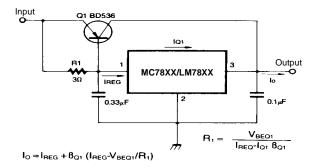


Figure 12. High Current Voltage Regulator

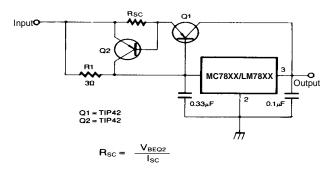


Figure 13. High Output Current with Short Circuit Protection

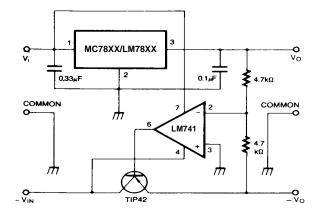


Figure 14. Tracking Voltage Regulator

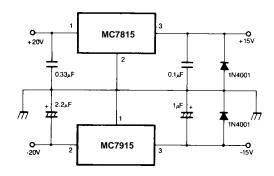


Figure 15. Split Power Supply (±15V-1A)

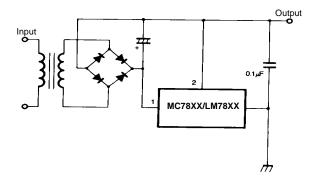


Figure 16. Negative Output Voltage Circuit

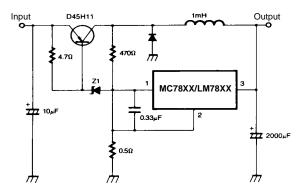
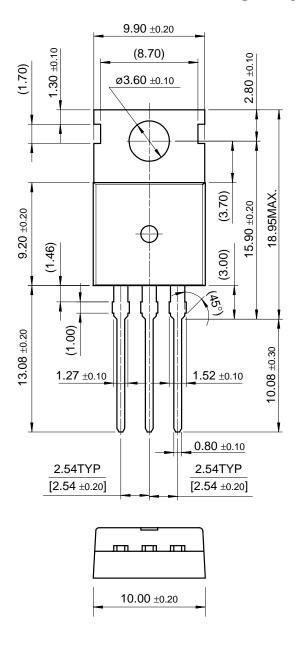


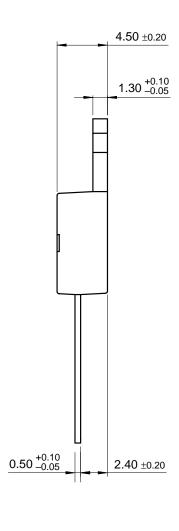
Figure 17. Switching Regulator

### **Mechanical Dimensions**

### Package

**TO-220** 

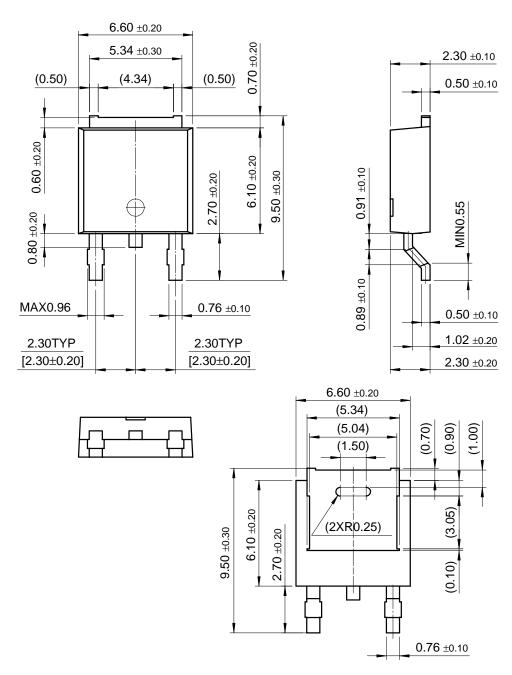




### **Mechancal Dimensions** (Continued)

### Package

# **D-PAK**



# **Ordering Information**

Product Number	Output Voltage Tolerance	Package	Operating Temperature
LM7805CT	±4%	TO-220	0 ~ + 125°C

Product Number	Output Voltage Tolerance	Package	Operating Temperature
MC7805CT			
MC7806CT			
MC7808CT			
MC7809CT			
MC7810CT		TO-220	
MC7812CT			
MC7815CT			
MC7818CT	±4%		
MC7824CT			
MC7805CDT			
MC7806CDT		D-PAK	
MC7808CDT			0 ~ + 125°C
MC7809CDT			0~+1250
MC7810CDT			
MC7812CDT			
MC7805ACT			
MC7806ACT			
MC7808ACT			
MC7809ACT			
MC7810ACT	±2%	TO-220	
MC7812ACT			
MC7815ACT			
MC7818ACT			
MC7824ACT			

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